

1. General description

Silicon Carbide Schottky diode with super-low capacitance in a SOD59A (TO-220AC) plastic package, designed for high frequency switched-mode power supplies.

2. Features and benefits

- Super low capacitance and recovery charge
- Highly stable switching performance
- High forward surge capability IFSM
- Extremely fast reverse recovery time
- Superior in efficiency to Silicon Diode alternatives
- Reduced losses in associated MOSFET
- Reduced EMI
- Reduced cooling requirements
- RoHS compliant

3. Applications

- Power factor correction
- Telecom / Server SMPS
- UPS
- PV inverter
- PC Silverbox
- LED / OLED TV
- Motor Drives

4. Quick reference data

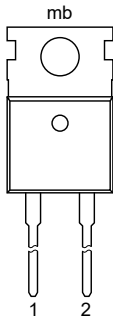
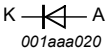
Table 1. Quick reference data

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
V _{RRM}	repetitive peak reverse voltage		-	-	650	V
I _{F(AV)}	average forward current	$\delta = 0.5$; $T_{mb} \leq 87$ °C; square-wave pulse; Fig. 1 ; Fig. 2 ; Fig. 3	-	-	10	A
T _j	junction temperature		-	-	175	°C
Static characteristics						
V _F	forward voltage	I _F = 10 A; T _j = 25 °C; Fig. 5	-	1.65	1.85	V
		I _F = 10 A; T _j = 150 °C; Fig. 5	-	2.1	2.5	V
Dynamic characteristics						

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
Q_r	recovered charge	$I_F = 10\text{ A}$; $di_F/dt = 500\text{ A}/\mu\text{s}$; $V_R = 400\text{ V}$; $T_j = 25\text{ }^\circ\text{C}$; Fig. 6	-	12	-	nC

5. Pinning information

Table 2. Pinning information

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	K	cathode	 <p>TO-220AC (SOD59A)</p>	
2	A	anode		
mb	mb	mounting base; connected to cathode		

6. Ordering information

Table 3. Ordering information

Type number	Package		
	Name	Description	Version
NXPLQSC10650	TO-220AC	Plastic single-ended package; heatsink mounted; 1 mounting hole; 2-lead TO-220AC	SOD59A

7. Marking

Table 4. Marking codes

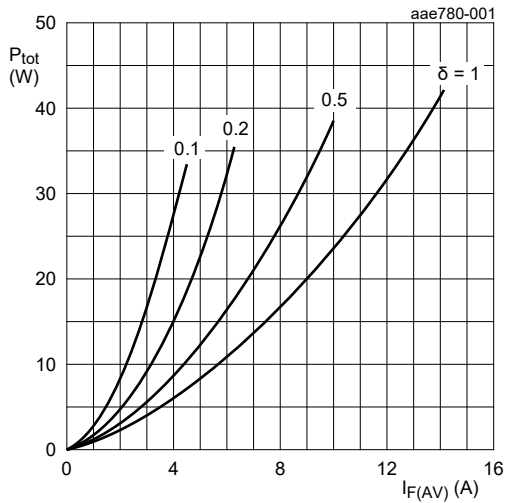
Type number	Marking code
NXPLQSC10650	NXPLQSC10650

8. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
V_{RRM}	repetitive peak reverse voltage		-	650	V
V_{RWM}	crest working reverse voltage		-	650	V
V_R	reverse voltage	DC	-	650	V
$I_{F(AV)}$	average forward current	$\delta = 0.5$; $T_{mb} \leq 87\text{ }^\circ\text{C}$; square-wave pulse; Fig. 1 ; Fig. 2 ; Fig. 3	-	10	A
I_{FRM}	repetitive peak forward current	$\delta = 0.5$; $t_p = 25\text{ }\mu\text{s}$; $T_{mb} \leq 87\text{ }^\circ\text{C}$; square-wave pulse	-	20	A
I_{FSM}	non-repetitive peak forward current	$t_p = 8.3\text{ ms}$; $T_{j(\text{init})} = 25\text{ }^\circ\text{C}$; sine-wave pulse	-	52	A
		$t_p = 10\text{ }\mu\text{s}$; $T_{j(\text{init})} = 25\text{ }^\circ\text{C}$; square-wave pulse	-	385	A
T_{stg}	storage temperature		-55	175	$^\circ\text{C}$
T_j	junction temperature		-	175	$^\circ\text{C}$



$$I_{F(AV)} = I_{F(RMS)} \times \sqrt{\delta}$$

$$V_o = 0.880\text{ V}; R_s = 0.148\text{ }\Omega$$

Fig. 1. Forward power dissipation as a function of average forward current; square waveform; maximum values

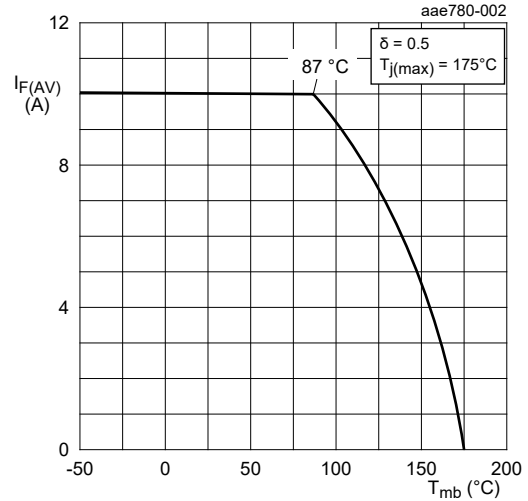


Fig. 2. Forward current as a function of mounting base temperature; maximum values

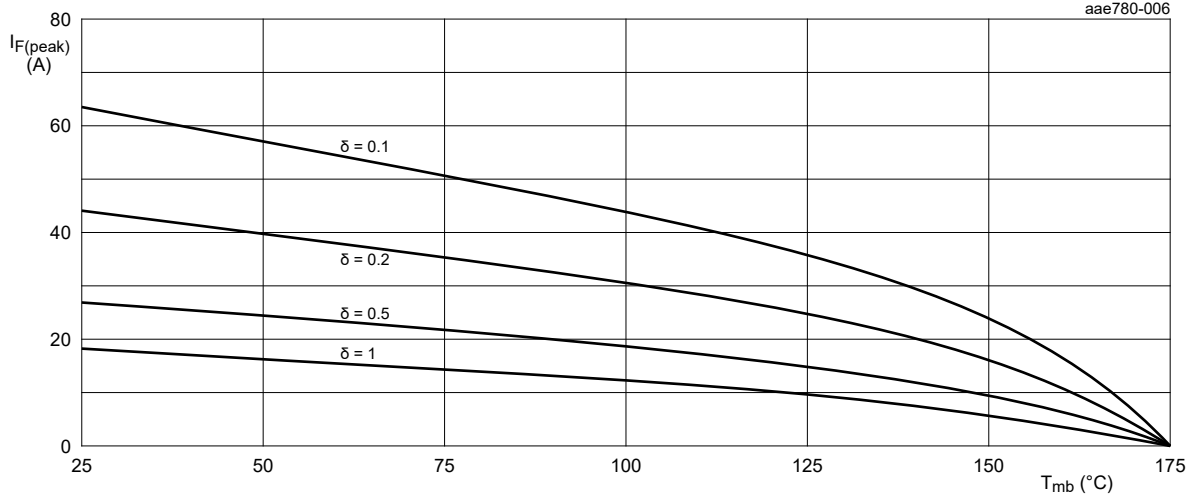


Fig. 3. Current derating as a function of mounting base temperature

9. Thermal characteristics

Table 6. Thermal characteristics

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
$R_{th(j-mb)}$	thermal resistance from junction to mounting base	Fig. 4	-	-	2.3	K/W
$R_{th(j-a)}$	thermal resistance from junction to ambient free air	in free air	-	60	-	K/W

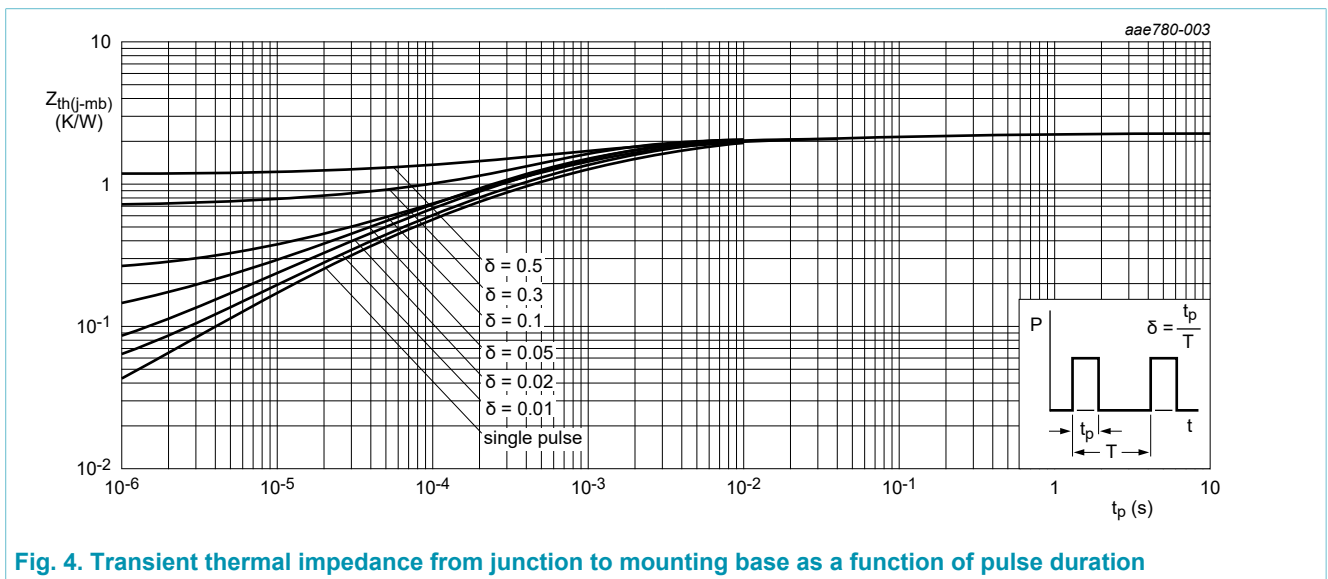
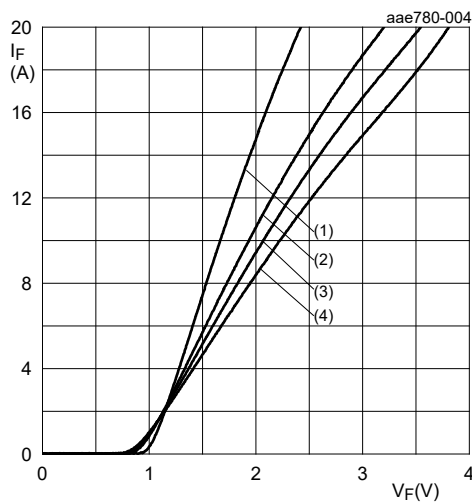


Fig. 4. Transient thermal impedance from junction to mounting base as a function of pulse duration

10. Characteristics

Table 7. Characteristics

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
Static characteristics						
V_F	forward voltage	$I_F = 10\text{ A}; T_j = 25\text{ }^\circ\text{C};$ Fig. 5	-	1.65	1.85	V
		$I_F = 10\text{ A}; T_j = 150\text{ }^\circ\text{C};$ Fig. 5	-	2.1	2.5	V
I_R	reverse current	$V_R = 650\text{ V}; T_j = 25\text{ }^\circ\text{C}$	-	-	230	μA
		$V_R = 650\text{ V}; T_j = 150\text{ }^\circ\text{C}$	-	-	700	μA
Dynamic characteristics						
Q_r	recovered charge	$I_F = 10\text{ A}; dI_F/dt = 500\text{ A}/\mu\text{s};$ $V_R = 400\text{ V}; T_j = 25\text{ }^\circ\text{C};$ Fig. 6	-	12	-	nC
C_d	diode capacitance	$f = 1\text{ MHz}; V_R = 1\text{ V}; T_j = 25\text{ }^\circ\text{C}$	-	250	-	pF
		$f = 1\text{ MHz}; V_R = 300\text{ V}; T_j = 25\text{ }^\circ\text{C}$	-	26	-	pF
		$f = 1\text{ MHz}; V_R = 600\text{ V}; T_j = 25\text{ }^\circ\text{C}$	-	21	-	pF



$V_o = 0.880\text{ V}; R_s = 0.148\ \Omega$
 (1) $T_j = 25\text{ }^\circ\text{C};$ typical values
 (2) $T_j = 100\text{ }^\circ\text{C};$ typical values
 (3) $T_j = 150\text{ }^\circ\text{C};$ typical values
 (4) $T_j = 175\text{ }^\circ\text{C};$ typical values

Fig. 5. Forward current as a function of forward voltage; typical values

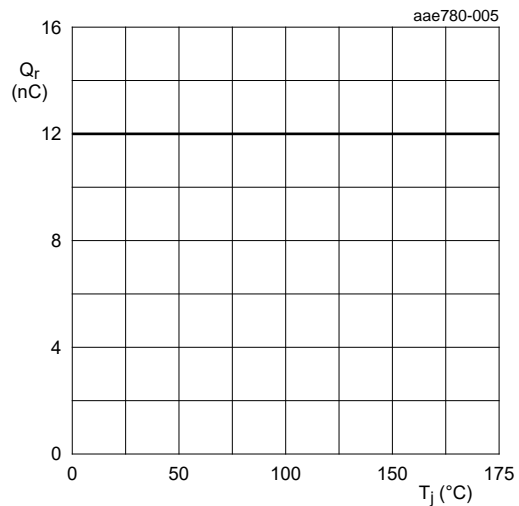
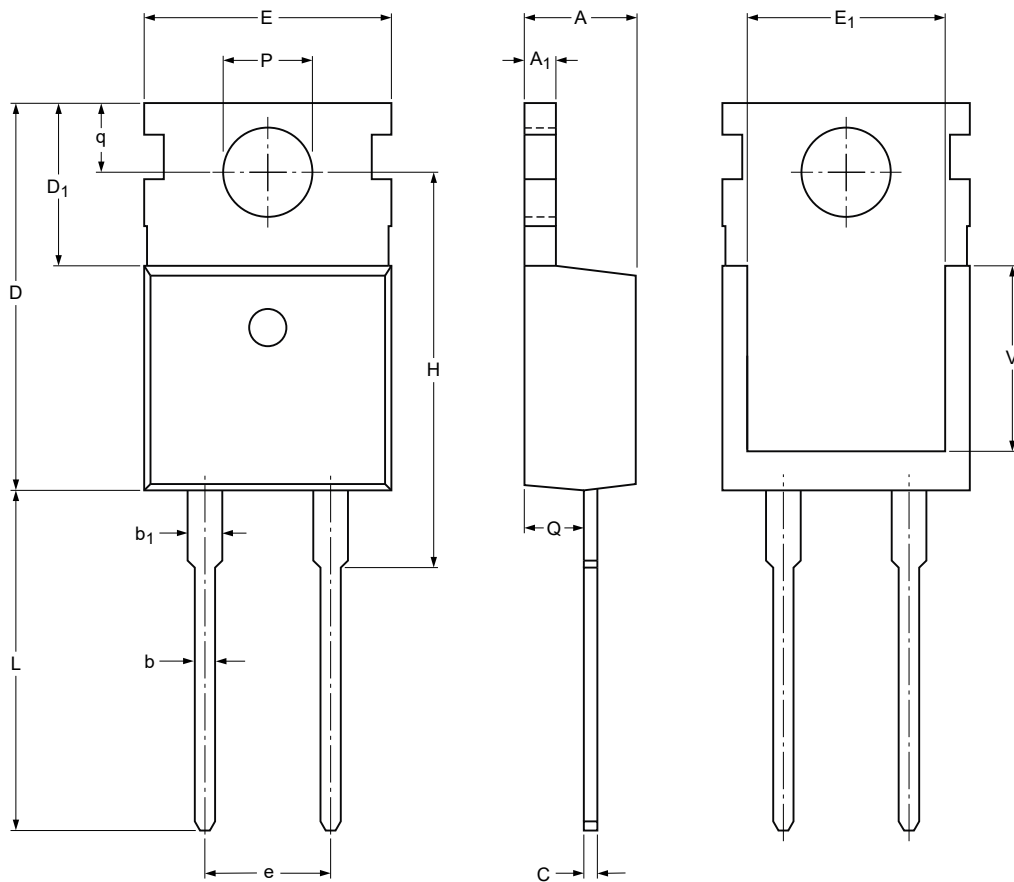


Fig. 6. Recovered charge as a function of junction temperature

11. Package outline

Plastic single-ended package; heatsink mounted; 1 mounting hole; 2-lead TO-220AC SOD59A



Dimensions: (mm are the original dimensions)

Unit	A	A ₁	b	b ₁ (¹)	c	D	D ₁	E	e	H	L	P	Q	q	E ₁	V
max	4.7	1.40	0.95	1.70	0.65	15.8	6.8	10.30	5.08	16.25	15.0	3.80	2.6	2.95	8.1	6.9
nom									(REF)							(REF)
min	4.3	1.15	0.70	1.17	0.45	15.6	6.4	9.65		15.70	12.5	3.53	2.2	2.65	7.9	

Note

1. Protruded dambar are included in the dimension.

sod059a_po

Outline version	References			European projection	Issue date
	IEC	JEDEC	JEITA		
SOD59A	TO-220AC (2-lead)				-15-03-24- 15-03-30

Fig. 7. Package outline TO-220AC (SOD59A)

12. Legal information

Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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- [2] The term 'short data sheet' is explained in section "Definitions".
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Date of release: 6 May 2016



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